

TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y LOW-DROPOUT VOLTAGE REGULATORS

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- Available in 5-V, 4.85-V, and 3.3-V Fixed-Output and Adjustable Versions
- Very Low-Dropout Voltage . . . Maximum of 32 mV at $I_O = 100$ mA (TPS7150)
- Very Low Quiescent Current – Independent of Load . . . 285 μ A Typ
- Extremely Low Sleep-State Current
0.5 μ A Max
- 2% Tolerance Over Full Range of Load, Line, and Temperature for Fixed-Output Versions
- Output Current Range of 0 mA to 500 mA
- TSSOP Package Option Offers Reduced Component Height for Critical Applications
- Power Good (PG) Status Output

description

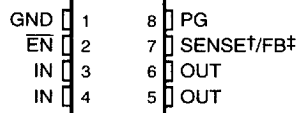
The TPS71xx integrated circuits are a family of micropower low-dropout (LDO) voltage regulators. An order of magnitude reduction in dropout voltage and quiescent current over conventional LDO performance is achieved by replacing the typical pnp pass transistor with a PMOS device.

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (maximum of 32 mV at an output current of 100 mA for the TPS7150) and is directly proportional to the output current (see Figure 1). Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and remains independent of output loading (typically 285 μ A over the full range of output current, 0 mA to 500 mA). These two key specifications yield a significant improvement in operating life for battery-powered systems. The LDO family also features a sleep mode; applying a TTL high signal to $\overline{\text{EN}}$ (enable) shuts down the regulator, reducing the quiescent current to 0.5 μ A maximum at $T_J = 25^\circ\text{C}$.

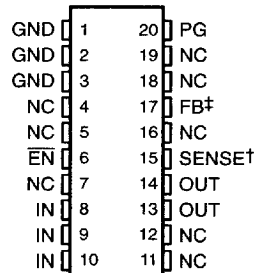
Power good (PG) reports low output voltage and can be used to implement a power-on reset or a low-battery indicator.

The TPS71xx is offered in 3.3-V, 4.85-V, and 5-V fixed-voltage versions and in an adjustable version (programmable over the range of 1.2 V to 9.75 V). Output voltage tolerance is specified as a maximum of 2% over line, load, and temperature ranges (3% for adjustable version). The TPS71xx family is available in PDIP (8 pin), SO (8 pin), and TSSOP (20 pin) packages. The TSSOP has a maximum height of 1.2 mm.

D OR P PACKAGE (TOP VIEW)



PW PACKAGE (TOP VIEW)



NC – No internal connection

† SENSE – Fixed voltage options only
(TPS7133, TPS7148, and TPS7150)

‡ FB – Adjustable version only (TPS7101)

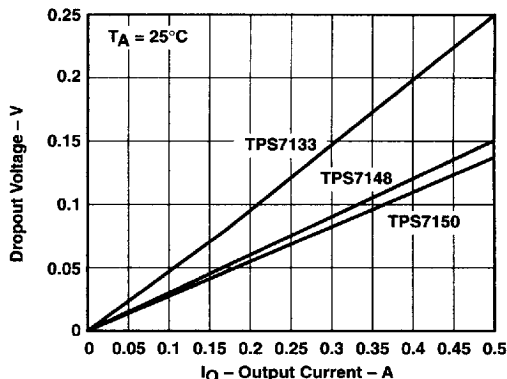


Figure 1. Dropout Voltage Versus Output Current

PRODUCTION DATA Information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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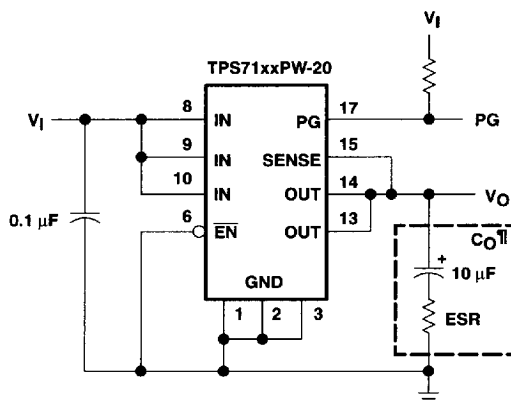
TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
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AVAILABLE OPTIONS

T_J	OUTPUT VOLTAGE (V)			PACKAGED DEVICES			CHIP FORM (Y)
	MIN	TYP	MAX	SMALL OUTLINE (D)	PLASTIC DIP (P)	TSSOP (PW)	
–55°C to 150°C	4.9	5	5.1	TPS7150QD	TPS7150QP	TPS7150QPWLE	TPS7150Y
	4.75	4.85	4.95	TPS7148QD	TPS7148QP	TPS7148QPWLE	TPS7148Y
	3.23	3.3	3.37	TPS7133QD	TPS7133QP	TPS7133QPWLE	TPS7133Y
	Adjustable [†] 1.2 V to 9.75 V			TPS7101QD	TPS7101QP	TPS7101QPWLE	TPS7101Y

The D package is available taped and reeled. Add R suffix to device type (e.g., TPS7150QDR). The PW package is only available left-end taped and reeled and is indicated by the LE suffix on the device type (i.e., TPS7150QPWLE). The TPS7101Q is programmable using an external resistor divider (see application information). The chip form is tested at 25°C.



[†] Capacitor selection is nontrivial. See application information section for details.

Figure 2. Typical Application Configuration

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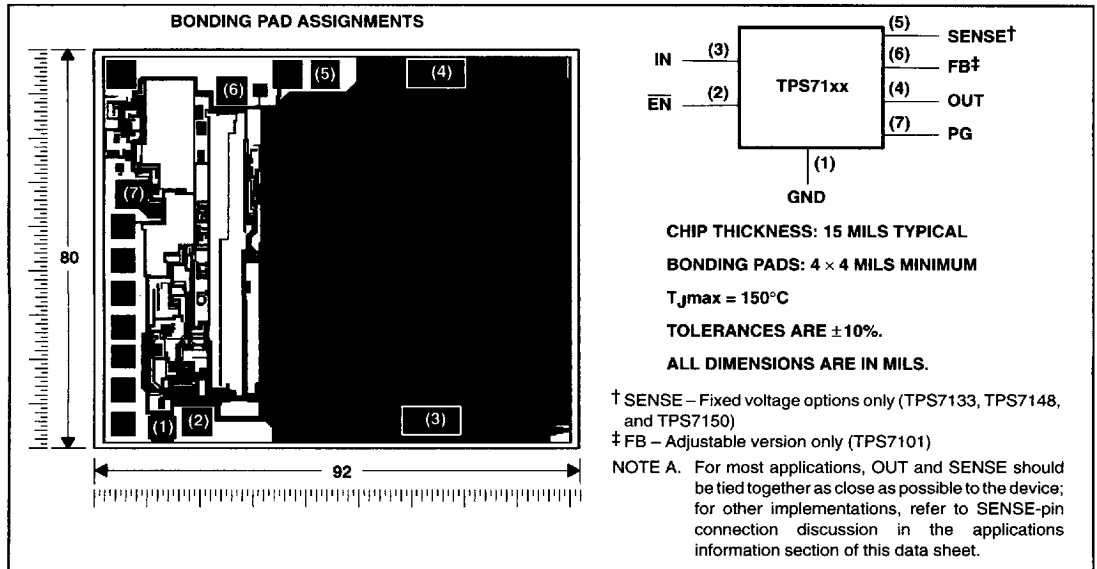
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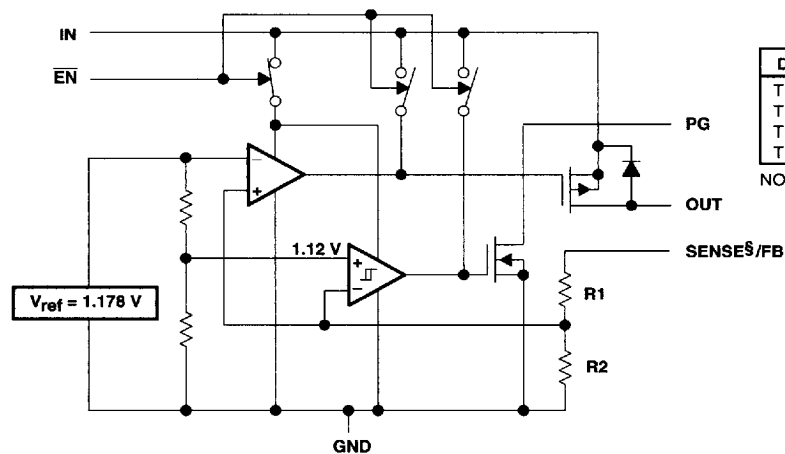
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TPS71xx chip information

These chips, when properly assembled, display characteristics similar to the TPS71xxQ. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chips may be mounted with conductive epoxy or a gold-silicon preform.



functional block diagram



RESISTOR DIVIDER OPTIONS

DEVICE	R1	R2	UNIT
TPS7101	0	∞	Ω
TPS7133	420	233	kΩ
TPS7148	726	233	kΩ
TPS7150	756	233	kΩ

NOTE: Resistors are nominal values only.

§ For most applications, SENSE should be externally connected to OUT as close as possible to the device. For other implementations, refer to SENSE-pin connection discussion in applications information section.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range‡, V_I , PG, SENSE, \overline{EN}	–0.3 to 10 V
Output current, I_O	2 A
Continuous total power dissipation	See Dissipation Rating Tables 1 and 2
Operating virtual junction temperature range, T_J	–55°C to 150°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

‡ All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURE (see Figure 3)

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	145 mW
P	1175 mW	9.4 mW/°C	752 mW	235 mW
PW§	700 mW	5.6 mW/°C	448 mW	140 mW

DISSIPATION RATING TABLE 2 – CASE TEMPERATURE (see Figure 4)

PACKAGE	$T_C \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_C = 25^\circ\text{C}$	$T_C = 70^\circ\text{C}$ POWER RATING	$T_C = 125^\circ\text{C}$ POWER RATING
D	2188 mW	17.5 mW/°C	1400 mW	438 mW
P	2738 mW	21.9 mW/°C	1752 mW	548 mW
PW§	4025 mW	32.2 mW/°C	2576 mW	805 mW

§ Refer to thermal information section for detailed power dissipation considerations when using the TSSOP package.

DISSIPATION DERATING CURVE
vs
FREE-AIR TEMPERATURE

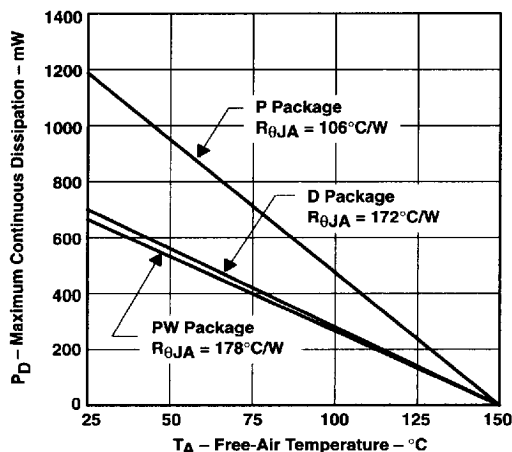


Figure 3

DISSIPATION DERATING CURVE
vs
CASE TEMPERATURE

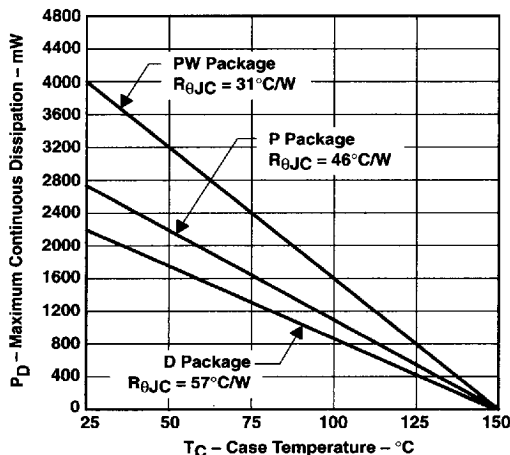


Figure 4

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recommended operating conditions

		MIN	MAX	UNIT
Input voltage, V_I^\dagger	TPS7101Q	2.5	10	V
	TPS7133Q	3.77	10	
	TPS7148Q	5.2	10	
	TPS7150Q	5.33	10	
High-level input voltage at \overline{EN} , V_{IH}		2		V
Low-level input voltage at \overline{EN} , V_{IL}			0.5	V
Output current range, I_O		0	500	mA
Operating virtual junction temperature range, T_J		-40	125	°C

† Minimum input voltage defined in the recommended operating conditions is the maximum specified output voltage plus dropout voltage at the maximum specified load range. Since dropout voltage is a function of output current, the usable range can be extended for lighter loads. To calculate the minimum input voltage for your maximum output current, use the following equation:

$$V_{I(\min)} = V_{O(\max)} + V_{DO(\max \text{ load})}$$

Because the TPS7101 is programmable, $r_{DS(on)}$ should be used to calculate V_{DO} before applying the above equation. The equation for calculating V_{DO} from $r_{DS(on)}$ is given in Note 2 in the electrical characteristics table. The minimum value of 2.5 V is the absolute lower limit for the recommended input voltage range for the TPS7101.

electrical characteristics at $I_O = 10 \text{ mA}$, $\overline{EN} = 0 \text{ V}$, $C_O = 4.7 \mu\text{F}/\text{ESR}^\dagger = 1 \Omega$, SENSE/FB shorted to OUT (unless otherwise noted)

PARAMETER	TEST CONDITIONS ‡	T_J	TPS7101Q, TPS7133Q TPS7148Q, TPS7150Q			UNIT
			MIN	TYP	MAX	
Ground current (active mode)	$\overline{EN} \leq 0.5 \text{ V}$, $0 \text{ mA} \leq I_O \leq 500 \text{ mA}$	25°C		285	350	μA
		-40°C to 125°C			460	
Input current (standby mode)	$\overline{EN} = V_I$, $2.7 \text{ V} \leq V_I \leq 10 \text{ V}$	25°C			0.5	μA
		-40°C to 125°C			2	
Output current limit	$V_O = 0 \text{ V}$, $V_I = 10 \text{ V}$	25°C		1.2	2	A
		-40°C to 125°C			2	
Pass-element leakage current in standby mode	$\overline{EN} = V_I$, $2.7 \text{ V} \leq V_I \leq 10 \text{ V}$	25°C			0.5	μA
		-40°C to 125°C			1	
PG leakage current	Normal operation, $V_{PG} = 10 \text{ V}$	25°C		0.02	0.5	μA
		-40°C to 125°C			0.5	
Output voltage temperature coefficient		-40°C to 125°C		61	75	ppm/°C
Thermal shutdown junction temperature				165		°C
\overline{EN} logic high (standby mode)	$2.5 \text{ V} \leq V_I \leq 6 \text{ V}$	-40°C to 125°C		2		V
	$6 \text{ V} \leq V_I \leq 10 \text{ V}$			2.7		
\overline{EN} logic low (active mode)	$2.7 \text{ V} \leq V_I \leq 10 \text{ V}$	25°C			0.5	V
		-40°C to 125°C			0.5	
\overline{EN} hysteresis voltage		25°C		50		mV
\overline{EN} input current *	$0 \text{ V} \leq V_I \leq 10 \text{ V}$	25°C	-0.5		0.5	μA
		-40°C to 125°C	-0.5		0.5	
Minimum V_I for active pass element		25°C		2.05	2.5	V
		-40°C to 125°C			2.5	
Minimum V_I for valid PG	$I_{PG} = 300 \mu\text{A}$	25°C		1.06	1.5	V
		-40°C to 125°C			1.9	

† ESR refers to the equivalent resistance, including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

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electrical characteristics at $I_O = 10\text{ mA}$, $V_I = 3.5\text{ V}$, $\overline{\text{EN}} = 0\text{ V}$, $C_O = 4.7\text{ }\mu\text{F/ESR}^\dagger = 1\text{ }\Omega$, FB shorted to OUT at device leads (unless otherwise noted)

PARAMETER	TEST CONDITIONS‡		T _J	TPS7101Q			UNIT
				MIN	TYP	MAX	
Reference voltage (measured at FB with OUT connected to FB)	$V_I = 3.5\text{ V}$, $2.5\text{ V} \leq V_I \leq 10\text{ V}$, See Note 1	$I_O = 10\text{ mA}$ $5\text{ mA} \leq I_O \leq 500\text{ mA}$	25°C		1.178		V
			–40°C to 125°C	1.143		1.213	V
Reference voltage temperature coefficient			–40°C to 125°C		61	75	ppm/°C
Pass-element series resistance (see Note 2)	$V_I = 2.4\text{ V}$, $150\text{ mA} \leq I_O \leq 500\text{ mA}$	$50\text{ }\mu\text{A} \leq I_O \leq 150\text{ mA}$	25°C		0.7	1	Ω
			–40°C to 125°C			1	
	$V_I = 2.4\text{ V}$, $50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	$150\text{ mA} \leq I_O \leq 500\text{ mA}$	25°C		0.83	1.3	
			–40°C to 125°C			1.3	
	$V_I = 2.9\text{ V}$, $50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	$50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	25°C		0.52	0.85	
			–40°C to 125°C			0.85	
	$V_I = 3.9\text{ V}$, $50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	$50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	25°C		0.32		
			25°C		0.23		
Input regulation	$V_I = 2.5\text{ V to } 10\text{ V}$, See Note 1	$50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	25°C			18	mV
			–40°C to 125°C			25	
Output regulation	$I_O = 5\text{ mA to } 500\text{ mA}$, See Note 1	$2.5\text{ V} \leq V_I \leq 10\text{ V}$, See Note 1	25°C			14	mV
			–40°C to 125°C			25	
	$I_O = 50\text{ }\mu\text{A to } 500\text{ mA}$, See Note 1	$2.5\text{ V} \leq V_I \leq 10\text{ V}$, See Note 1	25°C			22	mV
			–40°C to 125°C			54	
Ripple rejection	$f = 120\text{ Hz}$	$I_O = 50\text{ }\mu\text{A}$	25°C		48	59	dB
			–40°C to 125°C		44		
		$I_O = 500\text{ mA}$, See Note 1	25°C		45	54	
			–40°C to 125°C		44		
Output noise-spectral density	$f = 120\text{ Hz}$		25°C		2		$\mu\text{V}/\sqrt{\text{Hz}}$
Output noise voltage	$10\text{ Hz} \leq f \leq 100\text{ kHz}$, $\text{ESR}^\dagger = 1\text{ }\Omega$	$C_O = 4.7\text{ }\mu\text{F}$	25°C		95		μV_{rms}
		$C_O = 10\text{ }\mu\text{F}$	25°C		89		
		$C_O = 100\text{ }\mu\text{F}$	25°C		74		
PG trip-threshold voltage§	V_{FB} voltage decreasing from above V_{PG}		–40°C to 125°C	$0.92 \times V_{\text{FB(nom)}}$		$0.98 \times V_{\text{FB(nom)}}$	V
PG hysteresis voltage§	Measured at V_{FB}		25°C		12		mV
PG output low voltage§	$I_{\text{PG}} = 400\text{ }\mu\text{A}$, $V_I = 2.13\text{ V}$		25°C		0.1	0.4	V
			–40°C to 125°C			0.4	
FB input current			25°C	–10	0.1	10	nA
			–40°C to 125°C	–20		20	

† ESR refers to the equivalent resistance including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Output voltage programmed to 2.5 V with closed-loop configuration (see application information).

NOTES: 1. When $V_I < 2.9\text{ V}$ and $I_O > 150\text{ mA}$ simultaneously, pass element $r_{\text{DS(on)}}$ increases (see Figure 31) to a point such that the resulting dropout voltage prevents the regulator from maintaining the specified tolerance range.

2. To calculate dropout voltage, use equation:

$$V_{\text{DO}} = I_O \cdot r_{\text{DS(on)}}$$

$r_{\text{DS(on)}}$ is a function of both output current and input voltage. The parametric table lists $r_{\text{DS(on)}}$ for $V_I = 2.4\text{ V}$, 2.9 V , 3.9 V , and 5.9 V , which corresponds to dropout conditions for programmed output voltages of 2.5 V, 3 V, 4 V, and 6 V, respectively. For other programmed values, refer to Figure 30.

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electrical characteristics at $I_O = 10 \text{ mA}$, $V_I = 4.3 \text{ V}$, $\overline{\text{EN}} = 0 \text{ V}$, $C_O = 4.7 \mu\text{F}/\text{ESR}^\dagger = 1 \Omega$, SENSE shorted to OUT (unless otherwise noted)

PARAMETER	TEST CONDITIONS‡		T _J	TPS7133Q			UNIT
				MIN	TYP	MAX	
Output voltage	$V_I = 4.3 \text{ V}$, $I_O = 10 \text{ mA}$		25°C		3.3		V
	$4.3 \text{ V} \leq V_I \leq 10 \text{ V}$, $5 \text{ mA} \leq I_O \leq 500 \text{ mA}$		–40°C to 125°C	3.23		3.37	
Dropout voltage	$I_O = 10 \text{ mA}$, $V_I = 3.23 \text{ V}$		25°C		0.02	6	mV
			–40°C to 125°C			8	
	$I_O = 100 \text{ mA}$, $V_I = 3.23 \text{ V}$		25°C		47	60	
			–40°C to 125°C			80	
	$I_O = 500 \text{ mA}$, $V_I = 3.23 \text{ V}$		25°C		235	300	
			–40°C to 125°C			400	
Pass-element series resistance	$(3.23 \text{ V} - V_O)/I_O$, $I_O = 500 \text{ mA}$, $V_I = 3.23 \text{ V}$		25°C		0.47	0.6	Ω
			–40°C to 125°C			0.8	
Input regulation	$V_I = 4.3 \text{ V}$ to 10 V , $50 \mu\text{A} \leq I_O \leq 500 \text{ mA}$		25°C			20	mV
			–40°C to 125°C			27	
Output regulation	$I_O = 5 \text{ mA}$ to 500 mA , $4.3 \text{ V} \leq V_I \leq 10 \text{ V}$		25°C		21	38	mV
			–40°C to 125°C			75	
	$I_O = 50 \mu\text{A}$ to 500 mA , $4.3 \text{ V} \leq V_I \leq 10 \text{ V}$		25°C		30	60	mV
			–40°C to 125°C			120	
Ripple rejection	$f = 120 \text{ Hz}$	$I_O = 50 \mu\text{A}$	25°C	43	54		dB
			–40°C to 125°C	40			
		$I_O = 500 \text{ mA}$	25°C	39	49		
			–40°C to 125°C	36			
Output noise-spectral density	$f = 120 \text{ Hz}$		25°C		2		$\mu\text{V}/\sqrt{\text{Hz}}$
Output noise voltage	$10 \text{ Hz} \leq f \leq 100 \text{ kHz}$, $\text{ESR}^\dagger = 1 \Omega$	$C_O = 4.7 \mu\text{F}$	25°C		274		μV_{rms}
		$C_O = 10 \mu\text{F}$	25°C		228		
		$C_O = 100 \mu\text{F}$	25°C		159		
PG trip-threshold voltage	V_O voltage decreasing from above V_{PG}		–40°C to 125°C	$0.92 \times V_{O(\text{nom})}$		$0.98 \times V_{O(\text{nom})}$	V
PG hysteresis voltage			25°C		35		mV
PG output low voltage	$I_{\text{PG}} = 1 \text{ mA}$, $V_I = 2.8 \text{ V}$		25°C		0.22	0.4	V
			–40°C to 125°C			0.4	

† ESR refers to the equivalent resistance including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

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LOW-DROPOUT VOLTAGE REGULATORS

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electrical characteristics at $I_O = 10\text{ mA}$, $V_I = 5.85\text{ V}$, $\overline{EN} = 0\text{ V}$, $C_O = 4.7\text{ }\mu\text{F/ESR}^\dagger = 1\text{ }\Omega$, SENSE shorted to OUT (unless otherwise noted)

PARAMETER	TEST CONDITIONS [‡]	T _J	TPS7148Q			UNIT
			MIN	TYP	MAX	
Output voltage	$V_I = 5.85\text{ V}$, $I_O = 10\text{ mA}$	25°C		4.85		V
	$5.85\text{ V} \leq V_I \leq 10\text{ V}$, $5\text{ mA} \leq I_O \leq 500\text{ mA}$	–40°C to 125°C	4.75		4.95	
Dropout voltage	$I_O = 10\text{ mA}$, $V_I = 4.75\text{ V}$	25°C		0.08	6	mV
		–40°C to 125°C			8	
	$I_O = 100\text{ mA}$, $V_I = 4.75\text{ V}$	25°C		30	37	
		–40°C to 125°C			54	
	$I_O = 500\text{ mA}$, $V_I = 4.75\text{ V}$	25°C		150	180	
		–40°C to 125°C			250	
Pass-element series resistance	$(4.75\text{ V} - V_O)/I_O$, $I_O = 500\text{ mA}$, $V_I = 4.75\text{ V}$	25°C		0.32	0.35	Ω
		–40°C to 125°C			0.52	
Input regulation	$V_I = 5.85\text{ V to } 10\text{ V}$, $50\text{ }\mu\text{A} \leq I_O \leq 500\text{ mA}$	25°C			27	mV
		–40°C to 125°C			37	
Output regulation	$I_O = 5\text{ mA to } 500\text{ mA}$, $5.85\text{ V} \leq V_I \leq 10\text{ V}$	25°C		12	42	mV
		–40°C to 125°C			80	
	$I_O = 50\text{ }\mu\text{A to } 500\text{ mA}$, $5.85\text{ V} \leq V_I \leq 10\text{ V}$	25°C		42	60	mV
		–40°C to 125°C			130	
Ripple rejection	$f = 120\text{ Hz}$	$I_O = 50\text{ }\mu\text{A}$	25°C	42	53	dB
			–40°C to 125°C	39		
		$I_O = 500\text{ mA}$	25°C	39	50	
			–40°C to 125°C	35		
Output noise-spectral density	$f = 120\text{ Hz}$	25°C		2		$\mu\text{V}/\sqrt{\text{Hz}}$
Output noise voltage	$10\text{ Hz} \leq f \leq 100\text{ kHz}$, $\text{ESR}^\dagger = 1\text{ }\Omega$	$C_O = 4.7\text{ }\mu\text{F}$	25°C	410		μV_{rms}
		$C_O = 10\text{ }\mu\text{F}$	25°C	328		
		$C_O = 100\text{ }\mu\text{F}$	25°C	212		
PG trip-threshold voltage	V_O voltage decreasing from above V_{PG}	–40°C to 125°C	$0.92 \times V_{\text{O(nom)}}$		$0.98 \times V_{\text{O(nom)}}$	V
PG hysteresis voltage		25°C		50		mV
PG output low voltage	$I_{\text{PG}} = 1.2\text{ mA}$, $V_I = 4.12\text{ V}$	25°C		0.2	0.4	V
		–40°C to 125°C			0.4	

[†] ESR refers to the equivalent resistance including internal resistance and series resistance.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

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 **TEXAS
INSTRUMENTS**

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TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y
LOW-DROPOUT VOLTAGE REGULATORS

SLVS092C – NOVEMBER 1994 – REVISED AUGUST 1995

electrical characteristics at $I_O = 10\text{ mA}$, $V_I = 6\text{ V}$, $\overline{EN} = 0\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}$ /ESR $^\dagger = 1\text{ }\Omega$, SENSE shorted to OUT (unless otherwise noted)

PARAMETER	TEST CONDITIONS†		T _J	TPS7150Q			UNIT
				MIN	TYP	MAX	
Output voltage	V _I = 6 V,	I _O = 10 mA	25°C	5			V
	6 V ≤ V _I ≤ 10 V,	5 mA ≤ I _O ≤ 500 mA	−40°C to 125°C	4.9 5.1			
Dropout voltage	I _O = 10 mA,	V _I = 4.88 V	25°C	0.13 6			mV
			−40°C to 125°C	8			
	I _O = 100 mA,	V _I = 4.88 V	25°C	27 32			
			−40°C to 125°C	47			
	I _O = 500 mA,	V _I = 4.88 V	25°C	146 170			
			−40°C to 125°C	230			
Pass-element series resistance	(4.88 V − V _O)/I _O , I _O = 500 mA	V _I = 4.88 V.	25°C	0.29 0.32			Ω
			−40°C to 125°C	0.47			
Input regulation	V _I = 6 V to 10 V,	50 μA ≤ I _O ≤ 500 mA	25°C	25			mV
			−40°C to 125°C	32			
Output regulation	I _O = 5 mA to 500 mA,	6 V ≤ V _I ≤ 10 V	25°C	30 45			mV
			−40°C to 125°C	86			
	I _O = 50 μA to 500 mA,	6 V ≤ V _I ≤ 10 V	25°C	45 65			mV
			−40°C to 125°C	140			
Ripple rejection	f = 120 Hz	I _O = 50 μA	25°C	45 55			dB
			−40°C to 125°C	40			
		I _O = 500 mA	25°C	42 52			
			−40°C to 125°C	36			
Output noise-spectral density	f = 120 Hz		25°C	2			μV/√Hz
Output noise voltage	10 Hz ≤ f ≤ 100 kHz, ESR† = 1 Ω	C _O = 4.7 μF	25°C	430			μVrms
		C _O = 10 μF	25°C	345			
		C _O = 100 μF	25°C	220			
PG trip-threshold voltage	V _O voltage decreasing from above V _{PG}		−40°C to 125°C	0.92 × V _{O(nom)} 0.98 × V _{O(nom)}			V
PG hysteresis voltage			25°C	53			mV
PG output low voltage	I _{PG} = 1.2 mA,	V _I = 4.25 V	25°C	0.2 0.4			V
			−40°C to 125°C	0.4			

† ESR refers to the equivalent resistance including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

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TEXAS
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TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y
LOW-DROPOUT VOLTAGE REGULATORS

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electrical characteristics at $I_O = 10$ mA, $\overline{EN} = 0$ V, $C_O = 4.7$ μ F/ESR $^\dagger = 1$ Ω , $T_J = 25^\circ$ C, SENSE/FB shorted to OUT (unless otherwise noted)

PARAMETER	TEST CONDITIONS ‡	TPS7101Y, TPS7133Y TPS7148Y, TPS7150Y			UNIT
		MIN	TYP	MAX	
Ground current (active mode)	$\overline{EN} \leq 0.5$ V, $V_I = V_O + 1$ V, 0 mA $\leq I_O \leq 500$ mA		285		μ A
Output current limit	$V_O = 0$ V, $V_I = 10$ V		1.2		A
PG leakage current	Normal operation, $V_{PG} = 10$ V		0.02		μ A
Thermal shutdown junction temperature			165		$^\circ$ C
EN hysteresis voltage			50		mV
Minimum V_I for active pass element			2.05		V
Minimum V_I for valid PG	$I_{PG} = 300$ μ A		1.06		V

† ESR refers to the equivalent resistance, including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

PARAMETER	TEST CONDITIONS ‡	TPS7101Y			UNIT
		MIN	TYP	MAX	
Reference voltage (measured at FB with OUT connected to FB)	$V_I = 3.5$ V, $I_O = 10$ mA		1.178		V
Pass-element series resistance (see Note 2)	$V_I = 2.4$ V, 50 μ A $\leq I_O \leq 150$ mA		0.7		Ω
	$V_I = 2.4$ V, 150 mA $\leq I_O \leq 500$ mA		0.83		
	$V_I = 2.9$ V, 50 μ A $\leq I_O \leq 500$ mA		0.52		
	$V_I = 3.9$ V, 50 μ A $\leq I_O \leq 500$ mA		0.32		
	$V_I = 5.9$ V, 50 μ A $\leq I_O \leq 500$ mA		0.23		
Input regulation	$V_I = 2.5$ V to 10 V, See Note 1 50 μ A $\leq I_O \leq 500$ mA,			18	mV
Output regulation	2.5 V $\leq V_I \leq 10$ V, $I_O = 5$ mA to 500 mA, See Note 1			14	mV
	2.5 V $\leq V_I \leq 10$ V, $I_O = 50$ μ A to 500 mA, See Note 1			22	mV
Ripple rejection	$V_I = 3.5$ V, $I_O = 50$ μ A, $f = 120$ Hz,		59		dB
Output noise-spectral density	$V_I = 3.5$ V, $f = 120$ Hz		2		μ V/ \sqrt Hz
Output noise voltage	$V_I = 3.5$ V, 10 Hz $\leq f \leq 100$ kHz, ESR $^\dagger = 1$ Ω	$C_O = 4.7$ μ F	95		μ Vrms
		$C_O = 10$ μ F	89		
		$C_O = 100$ μ F	74		
PG hysteresis voltage §	$V_I = 3.5$ V, Measured at V_{FB}		12		mV
PG output low voltage §	$V_I = 2.13$ V, $I_{PG} = 400$ μ A		0.1		V
FB input current	$V_I = 3.5$ V		0.1		nA

† ESR refers to the equivalent resistance including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Output voltage programmed to 2.5 V with closed-loop configuration (see application information).

NOTES: 1 When $V_I < 2.9$ V and $I_O > 150$ mA simultaneously, pass element $r_{DS(on)}$ increases (see Figure 31) to a point such that the resulting dropout voltage prevents the regulator from maintaining the specified tolerance range.

2 To calculate dropout voltage, use equation:

$$V_{DO} = I_O \cdot r_{DS(on)}$$

$r_{DS(on)}$ is a function of both output current and input voltage. The parametric table lists $r_{DS(on)}$ for $V_I = 2.4$ V, 2.9 V, 3.9 V, and 5.9 V, which corresponds to dropout conditions for programmed output voltages of 2.5 V, 3 V, 4 V, and 6 V, respectively. For other programmed values, refer to Figure 30.

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TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y
LOW-DROPOUT VOLTAGE REGULATORS

SLVS092C – NOVEMBER 1994 – REVISED AUGUST 1995

electrical characteristics at $I_O = 10\text{ mA}$, $\overline{EN} = 0\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}/\text{ESR}^\dagger = 1\text{ }\Omega$, $T_J = 25^\circ\text{C}$, SENSE shorted to OUT (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS‡	TPS7133Y			UNIT
		MIN	TYP	MAX	
Output voltage	$V_I = 4.3\text{ V}$, $I_O = 10\text{ mA}$		3.3		V
Dropout voltage	$V_I = 3.23\text{ V}$, $I_O = 10\text{ mA}$		0.02		mV
	$V_I = 3.23\text{ V}$, $I_O = 100\text{ mA}$		47		
	$V_I = 3.23\text{ V}$, $I_O = 500\text{ mA}$		235		
Pass-element series resistance	$(3.23\text{ V} - V_O)/I_O$, $V_I = 3.23\text{ V}$, $I_O = 500\text{ mA}$		0.47		Ω
Output regulation	$4.3\text{ V} \leq V_I \leq 10\text{ V}$, $I_O = 5\text{ mA to } 500\text{ mA}$		21		mV
	$4.3\text{ V} \leq V_I \leq 10\text{ V}$, $I_O = 50\text{ }\mu\text{A to } 500\text{ mA}$		30		mV
Ripple rejection	$V_I = 4.3\text{ V}$, $f = 120\text{ Hz}$, $I_O = 50\text{ }\mu\text{A}$		54		dB
	$I_O = 500\text{ mA}$		49		
Output noise-spectral density	$V_I = 4.3\text{ V}$, $f = 120\text{ Hz}$		2		$\mu\text{V}/\sqrt{\text{Hz}}$
Output noise voltage	$V_I = 4.3\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}$		274		μVrms
	$10\text{ Hz} \leq f \leq 100\text{ kHz}$, $C_O = 10\text{ }\mu\text{F}$		228		
	$\text{ESR}^\dagger = 1\text{ }\Omega$, $C_O = 100\text{ }\mu\text{F}$		159		
PG hysteresis voltage	$V_I = 4.3\text{ V}$		35		mV
PG output low voltage	$V_I = 2.8\text{ V}$, $I_{PG} = 1\text{ mA}$		0.22		V

† ESR refers to the equivalent resistance including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

PARAMETER	TEST CONDITIONS‡	TPS7148Y			UNIT
		MIN	TYP	MAX	
Output voltage	$V_I = 5.85\text{ V}$, $I_O = 10\text{ mA}$		4.85		V
Dropout voltage	$V_I = 4.75\text{ V}$, $I_O = 10\text{ mA}$		0.08		mV
	$V_I = 4.75\text{ V}$, $I_O = 100\text{ mA}$		30		
	$V_I = 4.75\text{ V}$, $I_O = 500\text{ mA}$		150		
Pass-element series resistance	$(4.75\text{ V} - V_O)/I_O$, $V_I = 4.75\text{ V}$, $I_O = 500\text{ mA}$		0.32		Ω
Output regulation	$5.85\text{ V} \leq V_I \leq 10\text{ V}$, $I_O = 5\text{ mA to } 500\text{ mA}$		12		mV
	$5.85\text{ V} \leq V_I \leq 10\text{ V}$, $I_O = 50\text{ }\mu\text{A to } 500\text{ mA}$		42		mV
Ripple rejection	$V_I = 5.85\text{ V}$, $f = 120\text{ Hz}$, $I_O = 50\text{ }\mu\text{A}$		53		dB
	$I_O = 500\text{ mA}$		50		
Output noise-spectral density	$V_I = 5.85\text{ V}$, $f = 120\text{ Hz}$		2		$\mu\text{V}/\sqrt{\text{Hz}}$
Output noise voltage	$V_I = 5.85\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}$		410		μVrms
	$10\text{ Hz} \leq f \leq 100\text{ kHz}$, $C_O = 10\text{ }\mu\text{F}$		328		
	$\text{ESR}^\dagger = 1\text{ }\Omega$, $C_O = 100\text{ }\mu\text{F}$		212		
PG hysteresis voltage	$V_I = 5.85\text{ V}$		50		mV
PG output low voltage	$V_I = 4.12\text{ V}$, $I_{PG} = 1.2\text{ mA}$		0.2	0.4	V

† ESR refers to the equivalent resistance including internal resistance and series resistance.

‡ Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

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TEXAS
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TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
 TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y
 LOW-DROPOUT VOLTAGE REGULATORS

SLVS092C – NOVEMBER 1994 – REVISED AUGUST 1995

electrical characteristics at $I_O = 10\text{ mA}$, $\overline{EN} = 0\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}/\text{ESR}^\dagger = 1\text{ }\Omega$, $T_J = 25^\circ\text{C}$, SENSE shorted to OUT (unless otherwise noted) (continued)

PARAMETER	TEST CONDITIONS [‡]	TPS7150Y			UNIT
		MIN	TYP	MAX	
Output voltage	$V_I = 6\text{ V}$, $I_O = 10\text{ mA}$		5		V
Dropout voltage	$V_I = 4.88\text{ V}$, $I_O = 10\text{ mA}$		0.13		mV
	$V_I = 4.88\text{ V}$, $I_O = 100\text{ mA}$		27		
	$V_I = 4.88\text{ V}$, $I_O = 500\text{ }\mu\text{A}$		146		
Pass-element series resistance	$(4.88\text{ V} - V_O)/I_O$, $V_I = 4.88\text{ V}$, $I_O = 500\text{ mA}$		0.29		Ω
Output regulation	$6\text{ V} \leq V_I \leq 10\text{ V}$, $I_O = 5\text{ mA to } 500\text{ mA}$		30		mV
	$6\text{ V} \leq V_I \leq 10\text{ V}$, $I_O = 50\text{ }\mu\text{A to } 500\text{ mA}$		45		mV
Ripple rejection	$V_I = 6\text{ V}$, $f = 120\text{ Hz}$, $I_O = 50\text{ }\mu\text{A}$		55		dB
	$I_O = 500\text{ mA}$		52		
Output noise-spectral density	$V_I = 6\text{ V}$, $f = 120\text{ Hz}$		2		$\mu\text{V}/\sqrt{\text{Hz}}$
Output noise voltage	$V_I = 6\text{ V}$, $C_O = 4.7\text{ }\mu\text{F}$		430		μV_{rms}
	$10\text{ Hz} \leq f \leq 100\text{ kHz}$, $C_O = 10\text{ }\mu\text{F}$		345		
	$\text{ESR}^\dagger = 1\text{ }\Omega$, $C_O = 100\text{ }\mu\text{F}$		220		
PG hysteresis voltage	$V_I = 6\text{ V}$		53		mV
PG output low voltage	$V_I = 4.25\text{ V}$, $I_{\text{PG}} = 1.2\text{ mA}$		0.2		V

[†] ESR refers to the equivalent resistance including internal resistance and series resistance.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

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TYPICAL CHARACTERISTICS

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		39
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		41

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TYPICAL CHARACTERISTICS

QUIESCENT CURRENT
 vs
 OUTPUT CURRENT

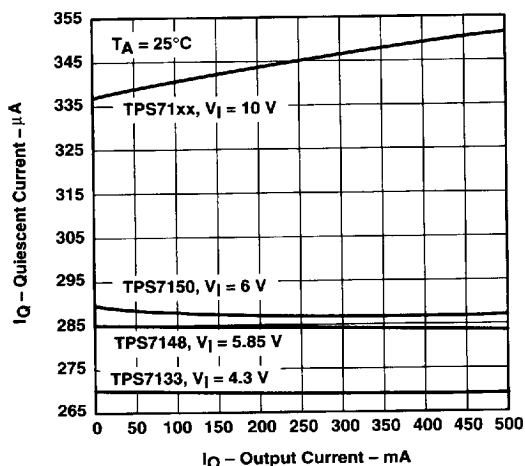


Figure 5

QUIESCENT CURRENT
 vs
 INPUT VOLTAGE

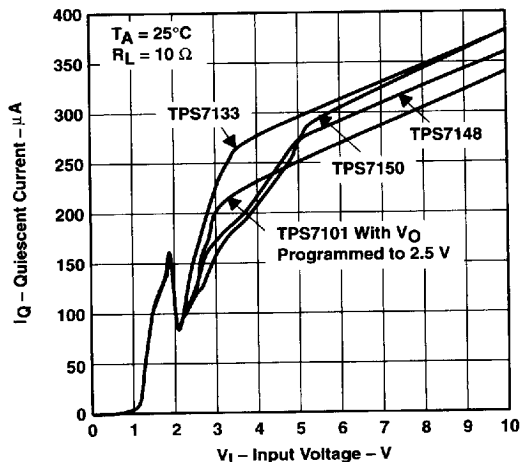


Figure 6

TPS7148Q
 QUIESCENT CURRENT
 vs
 FREE-AIR TEMPERATURE

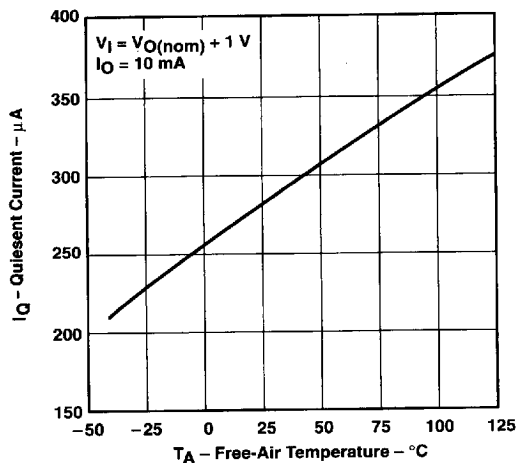


Figure 7

DROPOUT VOLTAGE
 vs
 OUTPUT CURRENT

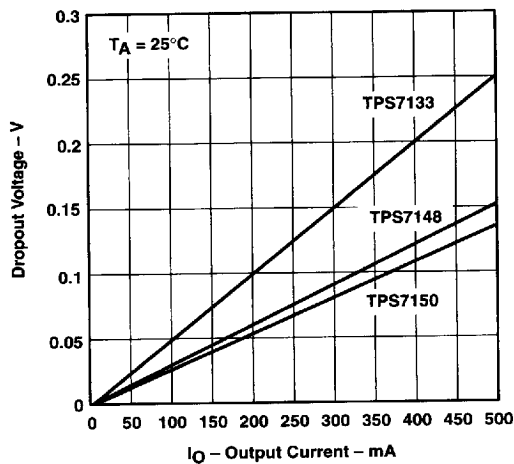


Figure 8

TYPICAL CHARACTERISTICS

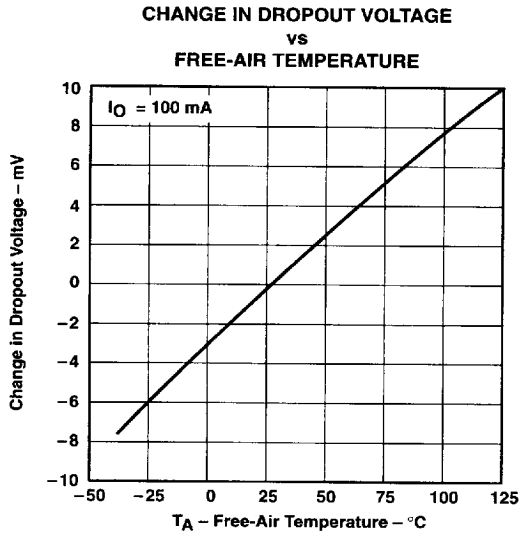


Figure 9

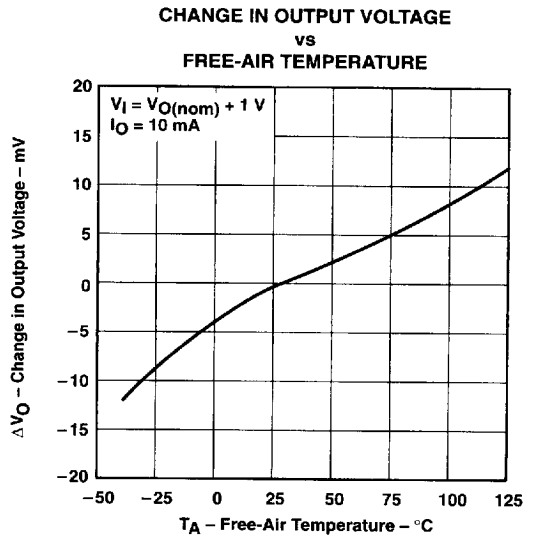


Figure 10

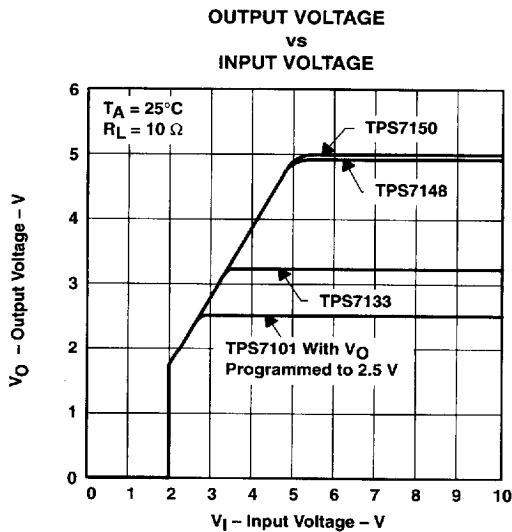


Figure 11

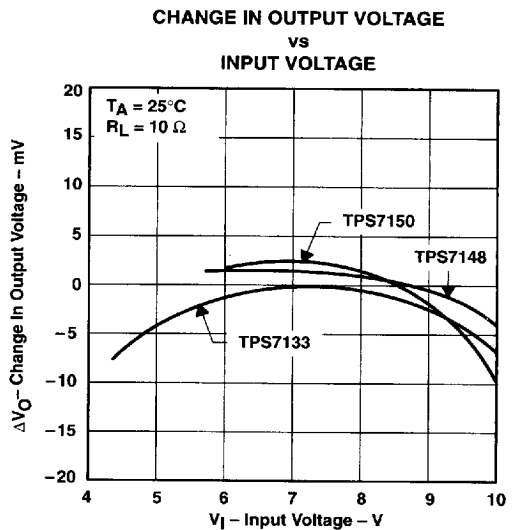
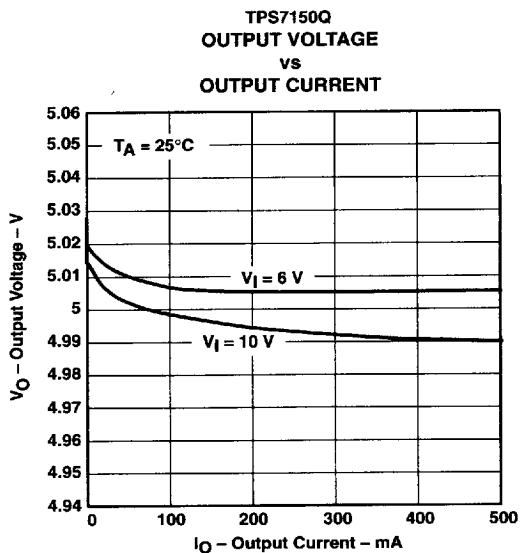
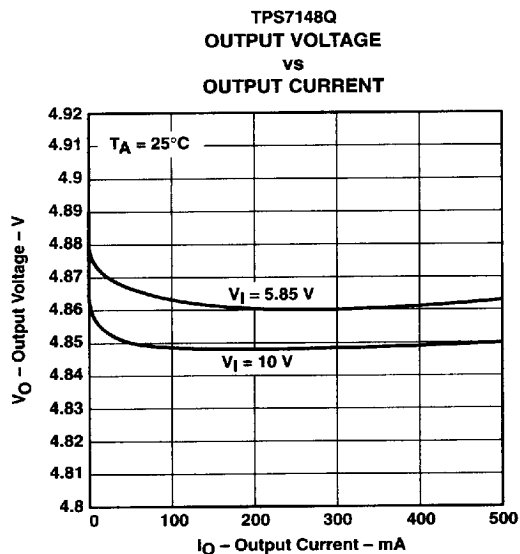
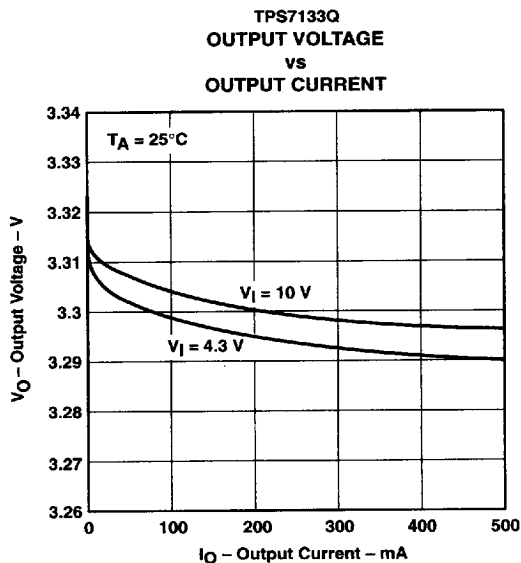
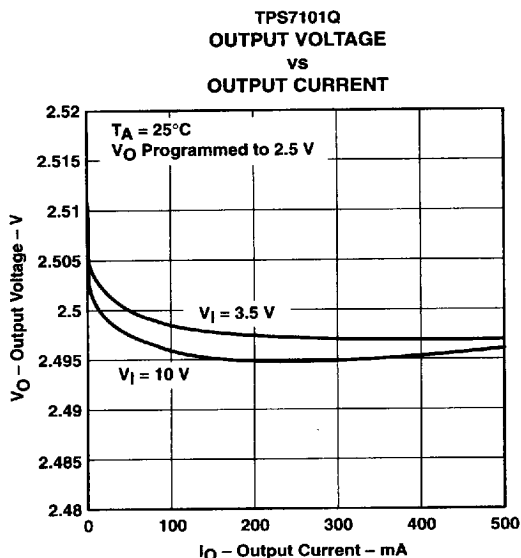


Figure 12

**TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y
LOW-DROPOUT VOLTAGE REGULATORS**

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TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

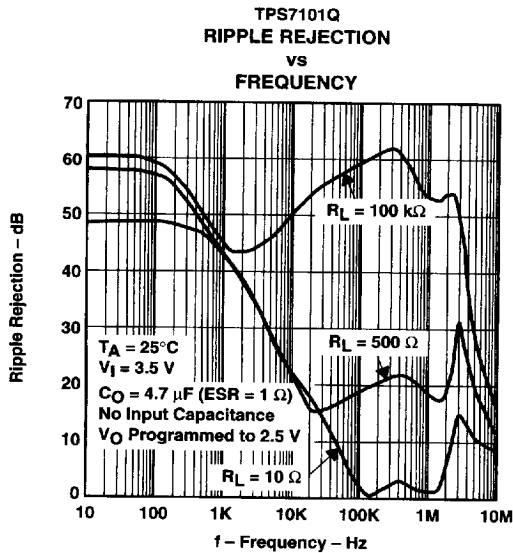


Figure 17

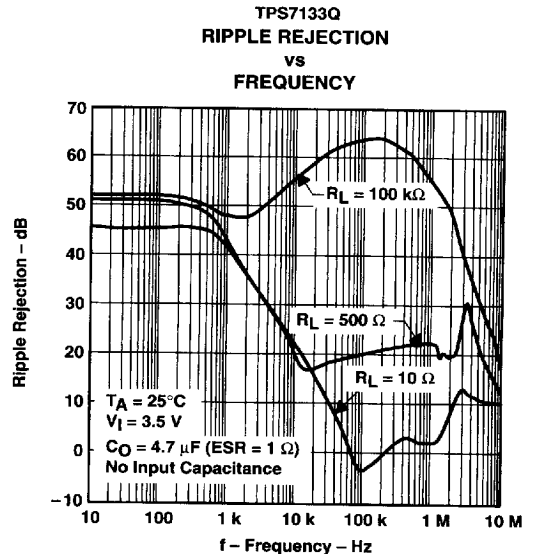


Figure 18

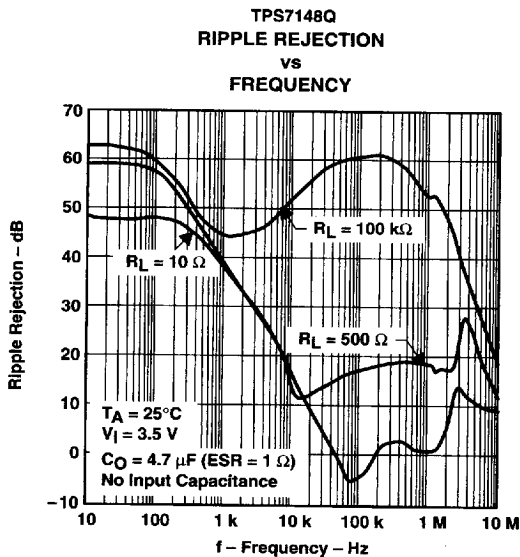


Figure 19

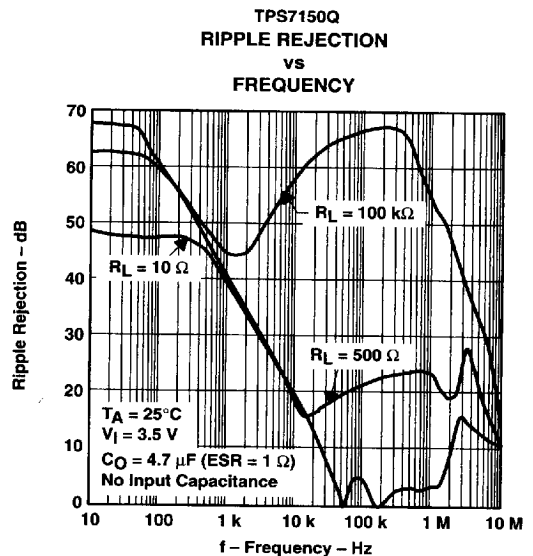


Figure 20

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TYPICAL CHARACTERISTICS

TPS7101Q
 OUTPUT SPECTRAL NOISE DENSITY
 vs
 FREQUENCY

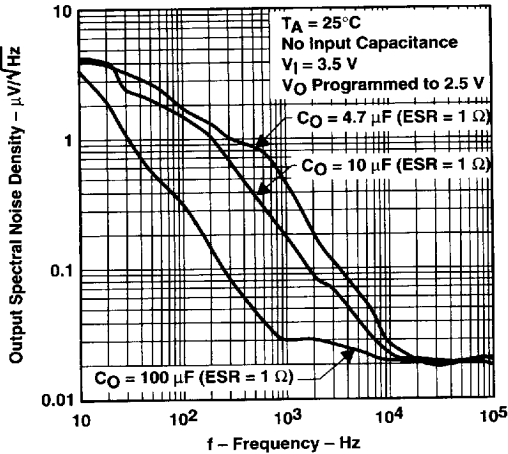


Figure 21

TPS7133Q
 OUTPUT SPECTRAL NOISE DENSITY
 vs
 FREQUENCY

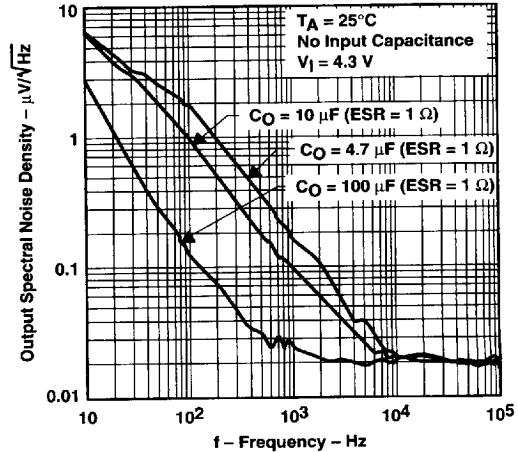


Figure 22

TPS7148Q
 OUTPUT SPECTRAL NOISE DENSITY
 vs
 FREQUENCY

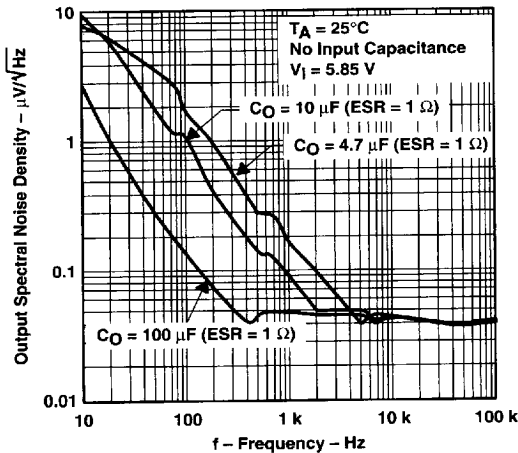


Figure 23

TPS7150Q
 OUTPUT SPECTRAL NOISE DENSITY
 vs
 FREQUENCY

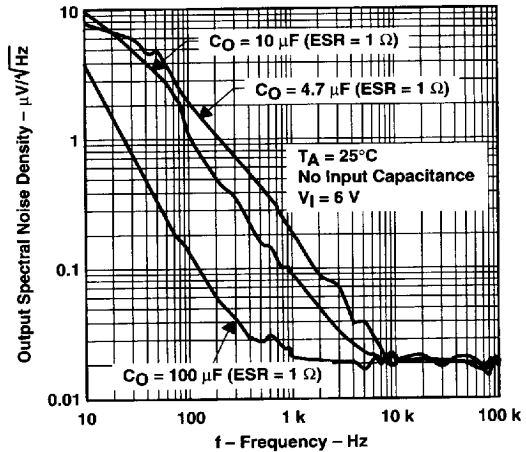


Figure 24

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TYPICAL CHARACTERISTICS

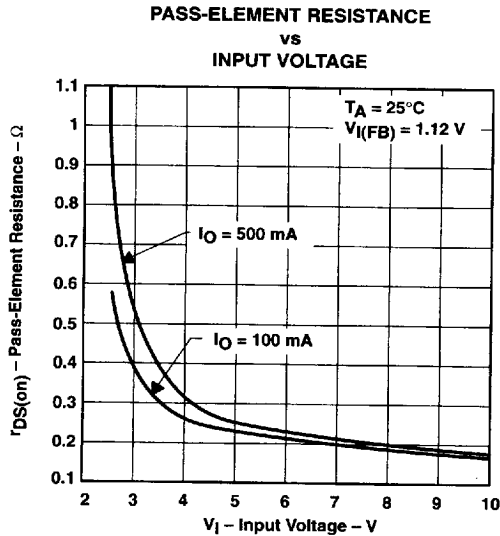


Figure 25

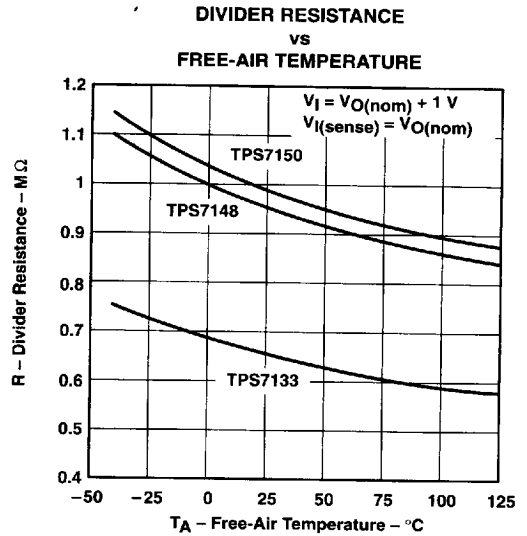


Figure 26

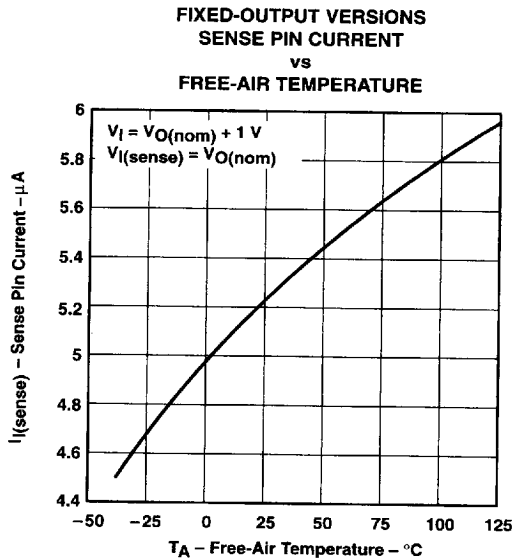


Figure 27

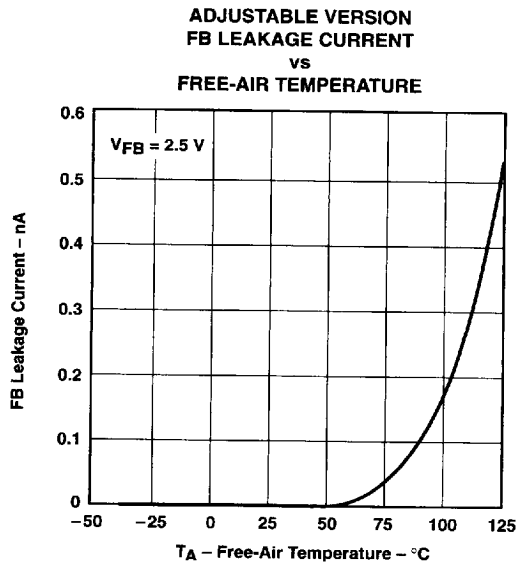


Figure 28

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TYPICAL CHARACTERISTICS

MINIMUM INPUT VOLTAGE FOR ACTIVE
 PASS ELEMENT
 vs
 FREE-AIR TEMPERATURE

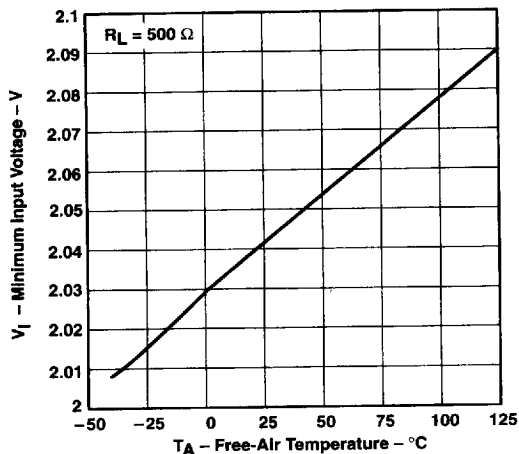


Figure 29

MINIMUM INPUT VOLTAGE FOR VALID
 POWER GOOD (PG)
 vs
 FREE-AIR TEMPERATURE

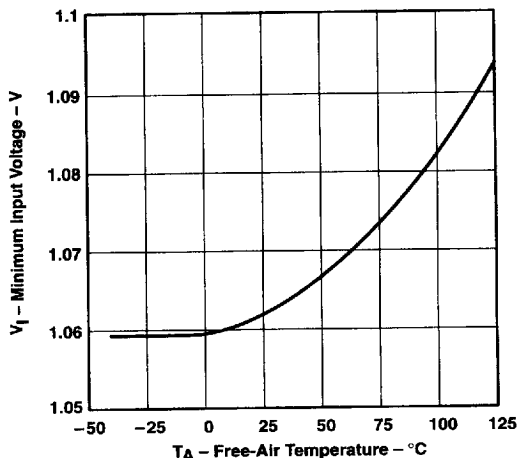


Figure 30

\overline{EN} INPUT CURRENT
 vs
 FREE-AIR TEMPERATURE

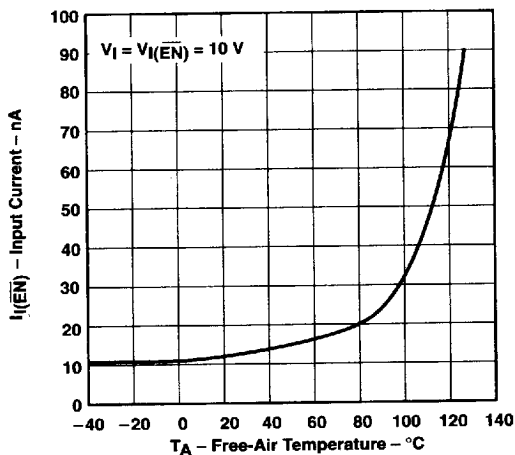


Figure 31

TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE RESPONSE FROM ENABLE (EN)

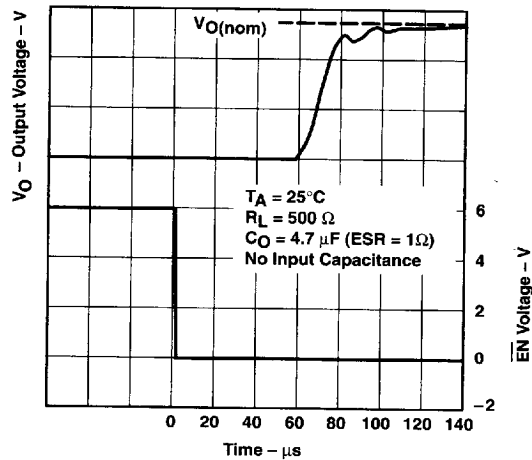


Figure 32

POWER-GOOD (PG) VOLTAGE vs OUTPUT VOLTAGE

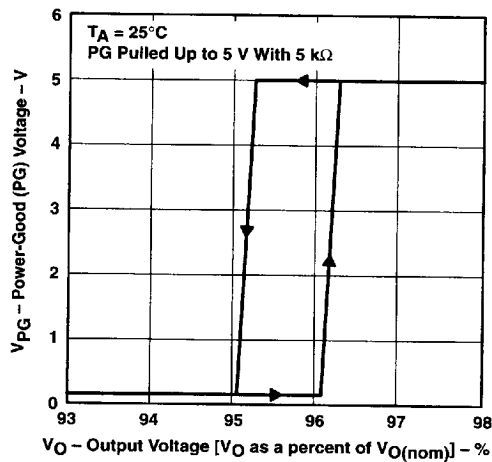


Figure 33

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TPS7101Q, TPS7133Q, TPS7148Q, TPS7150Q
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 LOW-DROPOUT VOLTAGE REGULATORS

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TYPICAL CHARACTERISTICS

TYPICAL REGIONS OF STABILITY
 TOTAL ESR
 vs
 OUTPUT CURRENT

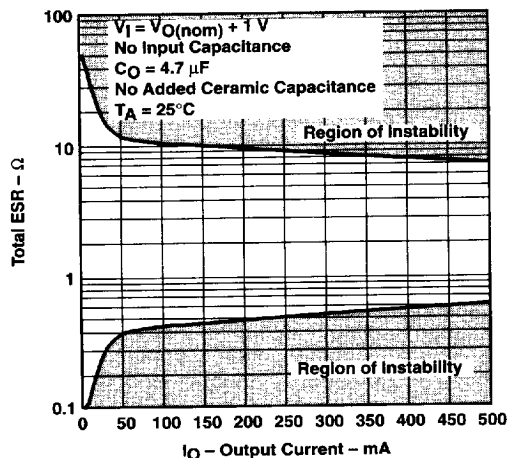


Figure 34

TYPICAL REGIONS OF STABILITY
 TOTAL ESR
 vs
 OUTPUT CURRENT

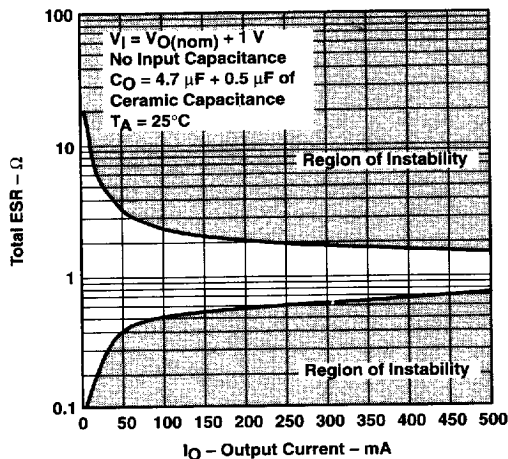


Figure 35

TYPICAL REGIONS OF STABILITY
 TOTAL ESR
 vs
 ADDED CERAMIC CAPACITANCE

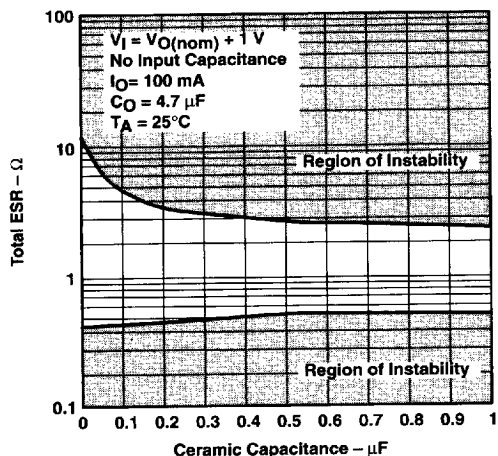


Figure 36

TYPICAL REGIONS OF STABILITY
 TOTAL ESR
 vs
 ADDED CERAMIC CAPACITANCE

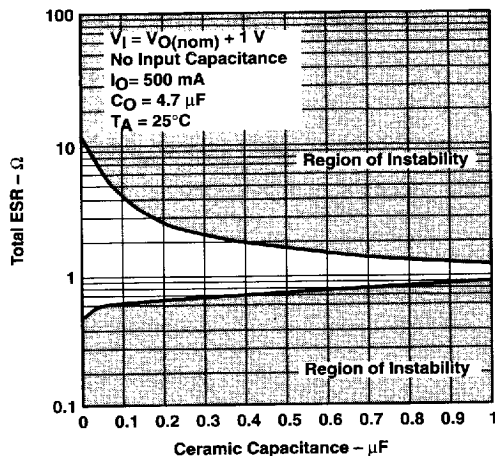


Figure 37

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TYPICAL CHARACTERISTICS

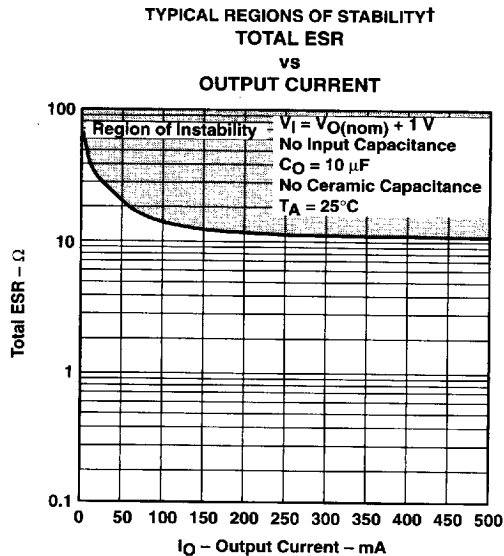


Figure 38

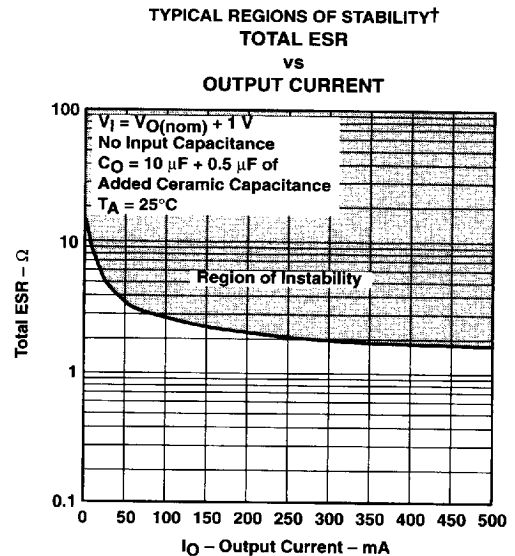


Figure 39

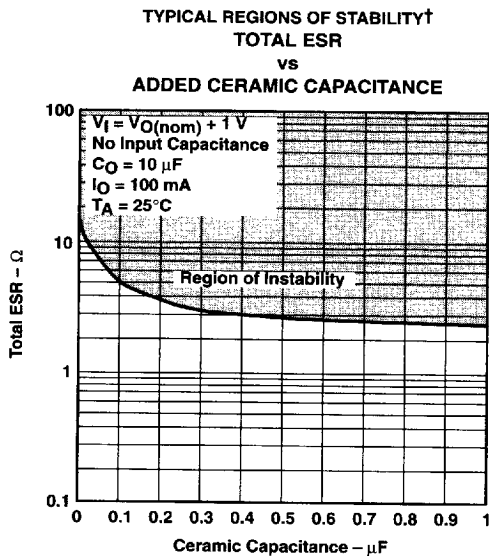


Figure 40

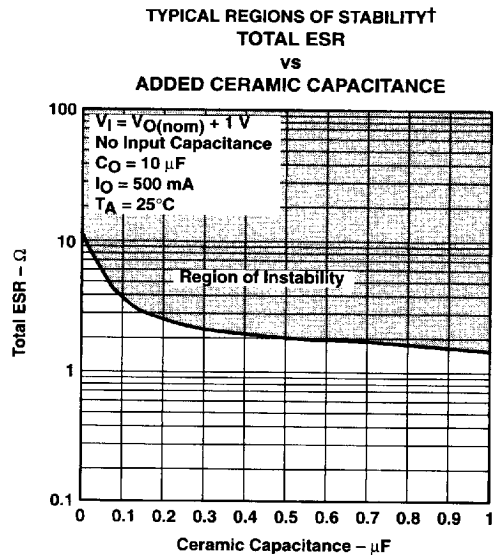
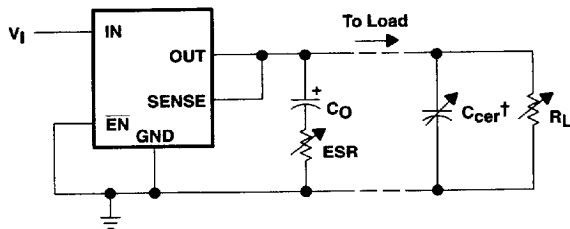


Figure 41

†ESR values below $0.1\text{ }\Omega$ are not recommended.

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TYPICAL CHARACTERISTICS



† Ceramic capacitor

Figure 42. Test Circuit for Typical Regions of Stability (Figures 39 through 46)

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THERMAL INFORMATION

In response to system-miniaturization trends, integrated circuits are being offered in low-profile and fine-pitch surface-mount packages. Implementation of many of today's high-performance devices in these packages requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are illustrated in this discussion:

- Improving the power-dissipation capability of the PWB design
- Improving the thermal coupling of the component to the PWB
- Introducing airflow in the system

Figure 43 is an example of a thermally enhanced PWB layout for the 20-lead TSSOP package. This layout involves adding copper on the PWB to conduct heat away from the device. The $R_{\theta JA}$ for this component/board system is illustrated in Figure 44. The family of curves illustrates the effect of increasing the size of the copper-heat-sink surface area. The PWB is a standard FR4 board ($L \times W \times H = 3.2 \text{ inch} \times 3.2 \text{ inch} \times 0.062 \text{ inch}$); the board traces and heat sink area are 1-oz (per square foot) copper.

Figure 45 shows the thermal resistance for the same system with the addition of a thermally conductive compound between the body of the TSSOP package and the PWB copper routed directly beneath the device. The thermal conductivity for the compound used in this analysis is $0.815 \text{ W/m} \cdot ^\circ\text{C}$.

Using these figures to determine the system $R_{\theta JA}$ allows the maximum power-dissipation limit to be calculated with the equation:

$$P_{D(\max)} = \frac{T_{J(\max)} - T_A}{R_{\theta JA(\text{system})}}$$

Where

$T_{J(\max)}$ is the maximum allowable junction temperature, (i.e., 150°C absolute maximum and 125°C maximum recommended operating temperature for specified operation).

This limit should then be applied to the internal power dissipated by the TPS71xx regulator. The equation for calculating total internal power dissipation of the TPS71xx is:

$$P_{D(\text{total})} = (V_I - V_O) \cdot I_O + V_I \cdot I_Q$$

Because the quiescent current of the TPS71xx family is very low, the second term is negligible, further simplifying the equation to:

$$P_{D(\text{total})} = (V_I - V_O) \cdot I_O$$

For a 20-lead TSSOP/FR4 board system with thermally conductive compound between the board and the device body, where $T_A = 55^\circ\text{C}$, airflow = 100 ft/min, copper heat sink area = 1 cm^2 , the maximum power-dissipation limit can be calculated. As indicated in Figure 45, the system $R_{\theta JA}$ is 94°C/W ; therefore, the maximum power-dissipation limit is:

$$P_{D(\max)} = \frac{T_{J(\max)} - T_A}{R_{\theta JA(\text{system})}} = \frac{125^\circ\text{C} - 55^\circ\text{C}}{94^\circ\text{C/W}} = 745 \text{ mW}$$

If the system implements a TPS7148 regulator where $V_I = 6 \text{ V}$ and $I_O = 385 \text{ mA}$, the internal power dissipation is:

$$P_{D(\text{total})} = (V_I - V_O) \cdot I_O = (6 - 4.85) \cdot 0.385 = 443 \text{ mW}$$

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 LOW-DROPOUT VOLTAGE REGULATORS

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Comparing $P_{D(\text{total})}$ with $P_{D(\text{max})}$ reveals that the power dissipation in this example does not exceed the maximum limit. When it does, one of two corrective actions can be taken. The power-dissipation limit can be raised by increasing the airflow or the heat-sink area. Alternatively, the internal power dissipation of the regulator can be lowered by reducing the input voltage or the load current. In either case, the above calculations should be repeated with the new system parameters.

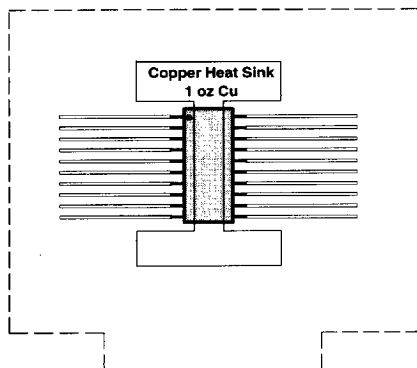


Figure 43. Thermally Enhanced PWB Layout (not to scale) for the 20-Pin TSSOP

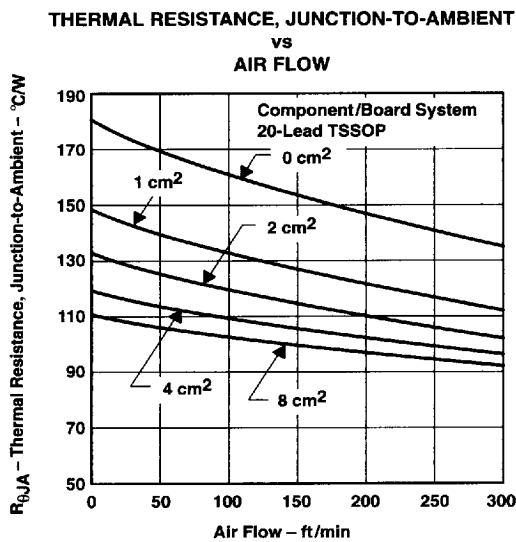


Figure 44

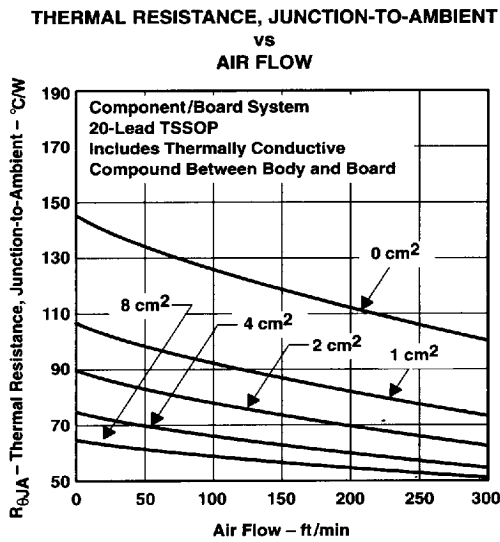


Figure 45

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APPLICATION INFORMATION

The TPS71xx series of low-dropout (LDO) regulators is designed to overcome many of the shortcomings of earlier-generation LDOs, while adding features such as a power-saving shutdown mode and a power-good indicator. The TPS71xx family includes three fixed-output voltage regulators: the TPS7133 (3.3 V), the TPS7148 (4.85 V), and the TPS7150 (5 V). The family also offers an adjustable device, the TPS7101 (adjustable from 1.2 V to 9.75 V).

device operation

The TPS71xx, unlike many other LDOs, features very low quiescent currents that remain virtually constant even with varying loads. Conventional LDO regulators use a pnp-pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). Close examination of the data sheets reveals that those devices are typically specified under near no-load conditions; actual operating currents are much higher as evidenced by typical quiescent current versus load current curves. The TPS71xx uses a PMOS transistor to pass current; because the gate of the PMOS element is voltage driven, operating currents are low and invariable over the full load range. The TPS71xx specifications reflect actual performance under load.

Another pitfall associated with the pnp-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS71xx quiescent current remains low even when the regulator drops out, eliminating both problems.

Included in the TPS71xx family is a 4.85-V regulator, the TPS7148. Designed specifically for 5-V cellular systems, its 4.85-V output, regulated to within $\pm 2\%$, allows for operation within the low-end limit of 5-V systems specified to $\pm 5\%$ tolerance; therefore, maximum regulated operating lifetime is obtained from a battery pack before the device drops out, adding crucial talk minutes between charges.

The TPS71xx family also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to under $2\ \mu\text{A}$. If the shutdown feature is not used, $\overline{\text{EN}}$ should be tied to ground. Response to an enable transition is quick; regulated output voltage is reestablished in typically $120\ \mu\text{s}$.

minimum load requirements

The TPS71xx family is stable even at zero load; no minimum load is required for operation.

SENSE-pin connection

The SENSE pin of fixed-output devices must be connected to the regulator output for proper functioning of the regulator. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit (remote sense) to improve performance at that point. Internally, SENSE connects to a high-impedance wide-bandwidth amplifier through a resistor-divider network and noise pickup feeds through to the regulator output. Routing the SENSE connection to minimize/avoid noise pickup is essential. Adding an RC network between SENSE and OUT to filter noise is not recommended because it can cause the regulator to oscillate.

external capacitor requirements

An input capacitor is not required; however, a ceramic bypass capacitor ($0.047\ \mu\text{F}$ to $0.1\ \mu\text{F}$) improves load transient response and noise rejection if the TPS71xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

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external capacitor requirements (continued)

As with most LDO regulators, the TPS71xx family requires an output capacitor for stability. A low-ESR 10- μ F solid-tantalum capacitor connected from the regulator output to ground is sufficient to ensure stability over the full load range (see Figure 46). Adding high-frequency ceramic or film capacitors (such as power-supply bypass capacitors for digital or analog ICs) can cause the regulator to become unstable unless the ESR of the tantalum capacitor is less than 1.2 Ω over temperature. Capacitors with published ESR specifications such as the AVX TPSD106K035R0300 and the Sprague 593D106X0035D2W work well because the maximum ESR at 25°C is 300 m Ω (typically, the ESR in solid-tantalum capacitors increases by a factor of 2 or less when the temperature drops from 25°C to -40°C). Where component height and/or mounting area is a problem, physically smaller, 10- μ F devices can be screened for ESR. Figures 34 through 41 show the stable regions of operation using different values of output capacitance with various values of ceramic load capacitance.

In applications with little or no high-frequency bypass capacitance (< 0.2 μ F), the output capacitance can be reduced to 4.7 μ F, provided ESR is maintained between 0.7 and 2.5 Ω . Because minimum capacitor ESR is seldom if ever specified, it may be necessary to add a 0.5- Ω to 1- Ω resistor in series with the capacitor and limit ESR to 1.5 Ω maximum. As shown in the ESR graphs (Figures 34 through 41), minimum ESR is not a problem when using 10- μ F or larger output capacitors.

Below is a partial listing of surface-mount capacitors usable with the TPS71xx family. This information (along with the ESR graphs, Figures 34 through 41) is included to assist in selection of suitable capacitance for the user's application. When necessary to achieve low height requirements along with high output current and/or high ceramic load capacitance, several higher ESR capacitors can be used in parallel to meet the guidelines above.

All load and temperature conditions with up to 1 μ F of added ceramic load capacitance:

PART NO.	MFR.	VALUE	MAX ESR†	SIZE (H \times L \times W)†
T421C226M010AS	Kemet	22 μ F, 10 V	0.5	2.8 \times 6 \times 3.2
593D156X0025D2W	Sprague	15 μ F, 25 V	0.3	2.8 \times 7.3 \times 4.3
593D106X0035D2W	Sprague	10 μ F, 35 V	0.3	2.8 \times 7.3 \times 4.3
TPSD106M035R0300	AVX	10 μ F, 35 V	0.3	2.8 \times 7.3 \times 4.3

Load < 200 mA, ceramic load capacitance < 0.2 μ F, full temperature range:

PART NO.	MFR.	VALUE	MAX ESR†	SIZE (H \times L \times W)†
592D156X0020R2T	Sprague	15 μ F, 20 V	1.1	1.2 \times 7.2 \times 6
595D156X0025C2T	Sprague	15 μ F, 25 V	1	2.5 \times 7.1 \times 3.2
595D106X0025C2T	Sprague	10 μ F, 25 V	1.2	2.5 \times 7.1 \times 3.2
293D226X0016D2W	Sprague	22 μ F, 16 V	1.1	2.8 \times 7.3 \times 4.3

Load < 100 mA, ceramic load capacitance < 0.2 μ F, full temperature range:

PART NO.	MFR.	VALUE	MAX ESR†	SIZE (H \times L \times W)†
195D106X006R3V2T	Sprague	10 μ F, 6.3 V	1.5	1.3 \times 3.5 \times 2.7
195D106X0016X2T	Sprague	10 μ F, 16 V	1.5	1.3 \times 7 \times 2.7
595D156X0016B2T	Sprague	15 μ F, 16 V	1.8	1.6 \times 3.8 \times 2.6
695D226X0015F2T	Sprague	22 μ F, 15 V	1.4	1.8 \times 6.5 \times 3.4
695D156X0020F2T	Sprague	15 μ F, 20 V	1.5	1.8 \times 6.5 \times 3.4
695D106X0035G2T	Sprague	10 μ F, 35 V	1.3	2.5 \times 7.6 \times 2.5

† Size is in mm. ESR is maximum resistance at 100 kHz and T_A = 25°C. Listings are sorted by height.

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APPLICATION INFORMATION

external capacitor requirements (continued)

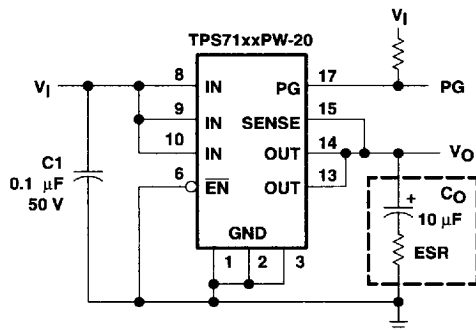


Figure 46. Typical Application Circuit

programming the TPS7101 adjustable LDO regulator

Programming the adjustable regulators is accomplished using an external resistor divider as shown in Figure 9. The equation governing the output voltage is:

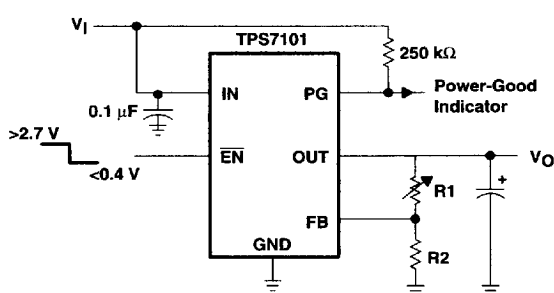
$$V_O = V_{\text{ref}} \cdot \left(1 + \frac{R_1}{R_2}\right) \quad (1)$$

where

V_{ref} = reference voltage, 1.178 V typ

Resistors R1 and R2 should be chosen for approximately 7-µA divider current. A recommended value for R2 is 169 kΩ with R1 adjusted for the desired output voltage. Smaller resistors can be used, but offer no inherent advantage and consume more power. Larger values of R1 and R2 should be avoided as leakage currents at FB will introduce an error. Solving equation 1 for R1 yields a more useful equation for choosing the appropriate resistance:

$$R_1 = \left(\frac{V_O}{V_{\text{ref}}} - 1\right) \cdot R_2 \quad (2)$$



OUTPUT VOLTAGE
PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	191	169	kΩ
3.3 V	309	169	kΩ
3.6 V	348	169	kΩ
4 V	402	169	kΩ
5 V	549	169	kΩ
6.4 V	750	169	kΩ

Figure 47. TPS7101 Adjustable LDO Regulator Programming

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TPS7101Y, TPS7133Y, TPS7148Y, TPS7150Y
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power-good indicator

The TPS71xx features a power-good (PG) output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the PG output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. PG can be used to drive power-on reset circuitry or as a low-battery indicator. PG does not assert itself when the regulated output voltage falls outside the specified 2% tolerance, but instead reports an output voltage low, relative to its nominal regulated value.

regulator protection

The TPS71xx PMOS-pass transistor has a built-in back diode that safely conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS71xx also features internal current limiting and thermal protection. During normal operation, the TPS71xx limits output current to approximately 1 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 165°C, thermal-protection circuitry shuts it down. Once the device has cooled, regulator operation resumes.

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